

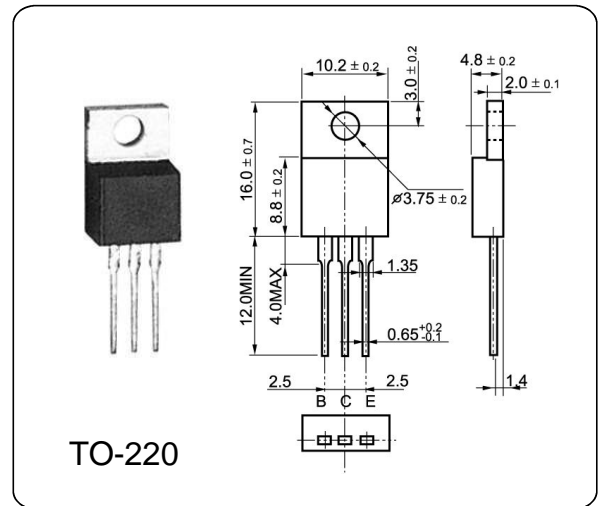


### DESCRIPTION

It is intended for use in power amplifier and switching applications.

### ABSOLUTE MAXIMUM RATINGS ( Ta = 25 °C)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	60	V
Collector-Emitter Voltage	$V_{CEO}$	60	V
Emitter-Base Voltage	$V_{EBO}$	7	V
Collector Current	$I_C$	3.0	A
Base Current	$I_B$	0.5	A
Total Dissipation at	$P_{tot}$	30	W
Max. Operating Junction Temperature	$T_j$	150	°C
Storage Temperature	$T_{stg}$	-55~150	°C



### ELECTRICAL CHARACTERISTICS (Ta = 25 °C)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector Cut-off Current	$I_{CEO}$	$V_{CB}=60V, I_E=0$			0.1	mA
Emitter Cut-off Current	$I_{EBO}$	$V_{EB}=7V, I_C=0$			0.1	mA
Collector-Emitter Sustaining Voltage	$V_{CEO}$	$I_C=50mA, I_B=0$	60			V
DC Current Gain	$h_{FE(1)}$	$V_{CE}=4V, I_C=1.0A$	25			
	$h_{FE(2)}$	$V_{CE}=4V, I_C=3.0A$	10		50	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=3A, I_B=300mA$			1.0	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}$	$V_{CE}=5V, I_C=0.5A$			1.0	V
Current Gain Bandwidth Product	$f_T$	$V_{CE}=5V, I_C=500mA$	3			MHz